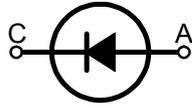
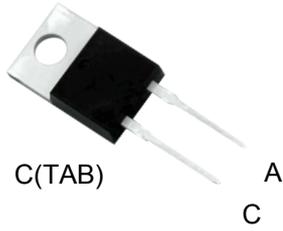


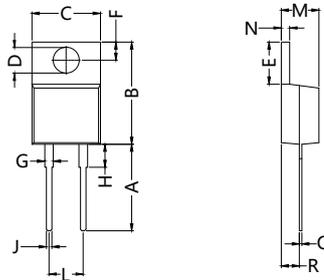
MUR1520

Ultra Fast Recovery Diodes



A=Anode, C=Cathode, TAB=Cathode

Dimensions TO-220AC



Dim.	Millimeter	
	Min.	Max.
A	12.70	13.97
B	14.73	16.00
C	9.91	10.66
ØD	3.54	4.08
E	5.85	6.85
F	2.54	3.18
G	1.15	1.65
H	2.79	5.84
J	0.64	1.01
L	5.05BSC	
M	4.32	4.82
N	1.14	1.39
Q	0.35	0.56
R	2.29	2.79

	V _{RSM} V	V _{RRM} V
MUR1520	200	200

Symbol	Test Conditions	Maximum Ratings	Unit
I _{FRMS} I _{FAVM} I _{FRM}	T _{VJ} =T _{VJM} T _C =100°C; rectangular, d=0.5 t _p <10us; rep. rating, pulse width limited by T _{VJM}	25 15 150	A
I _{FSM}	T _{VJ} =45°C t=10ms (50Hz), sine t=8.3ms (60Hz), sine	150 160	A
	T _{VJ} =150°C t=10ms(50Hz), sine t=8.3ms(60Hz), sine	95 105	
I ² t	T _{VJ} =45°C t=10ms (50Hz), sine t=8.3ms (60Hz), sine	50 50	A ² s
	T _{VJ} =150°C t=10ms(50Hz), sine t=8.3ms(60Hz), sine	36 37	
T _{VJ} T _{VJM} T _{stg}		-40...+150 150 -40...+150	°C
P _{tot}	T _C =25°C	62	W
M _d	Mounting torque	0.4...0.6	Nm
Weight		2	g

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Ultra Fast Recovery Diodes

Symbol	Test Conditions	Characteristic Values		Unit
		typ.	max.	
I_R	$T_{VJ}=25^{\circ}\text{C}; V_R=V_{RRM}$		10	μA
	$T_{VJ}=25^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$		10	μA
	$T_{VJ}=125^{\circ}\text{C}; V_R=0.8 \cdot V_{RRM}$		1	mA
V_F	$I_F=15\text{A}; T_{VJ}=150^{\circ}\text{C}$		1.0	V
	$T_{VJ}=25^{\circ}\text{C}$		1.2	
V_{FO}	For power-loss calculations only		1.12	V
r_F	$T_{VJ}=T_{VJM}$		23.2	$\text{m}\Omega$
R_{thJC} R_{thCK} R_{thJA}		0.5	2	K/W
			60	
t_{tr}	$I_F=1\text{A}; -di/dt=50\text{A}/\mu\text{s}; V_R=30\text{V}; T_{VJ}=25^{\circ}\text{C}$	35	50	ns
I_{RM}	$V_R=350\text{V}; I_F=15\text{A}; -di_F/dt=100\text{A}/\mu\text{s}; L \leq 0.05\mu\text{H}; T_{VJ}=100^{\circ}\text{C}$	4	4.4	A

FEATURES

- * International standard package TO-220AC
- * Glass passivated chips
- * Very short recovery time
- * Extremely low switching losses
- * Low I_{RM} -values
- * Soft recovery behaviour
- * RoHS compliant

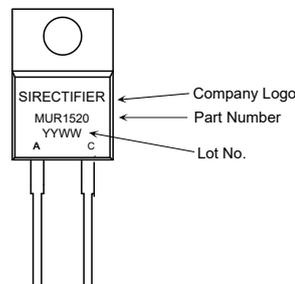
APPLICATIONS

- * Antiparallel diode for high frequency switching devices
- * Antisaturation diode
- * Snubber diode
- * Free wheeling diode in converters and motor control circuits
- * Rectifiers in switch mode power supplies (SMPS)
- * Inductive heating and melting
- * Uninterruptible power supplies (UPS)
- * Ultrasonic cleaners and welders

ADVANTAGES

- * High reliability circuit operation
- * Low voltage peaks for reduced protection circuits
- * Low noise switching
- * Low losses
- * Operating at lower temperature or space saving by reduced cooling

Marking

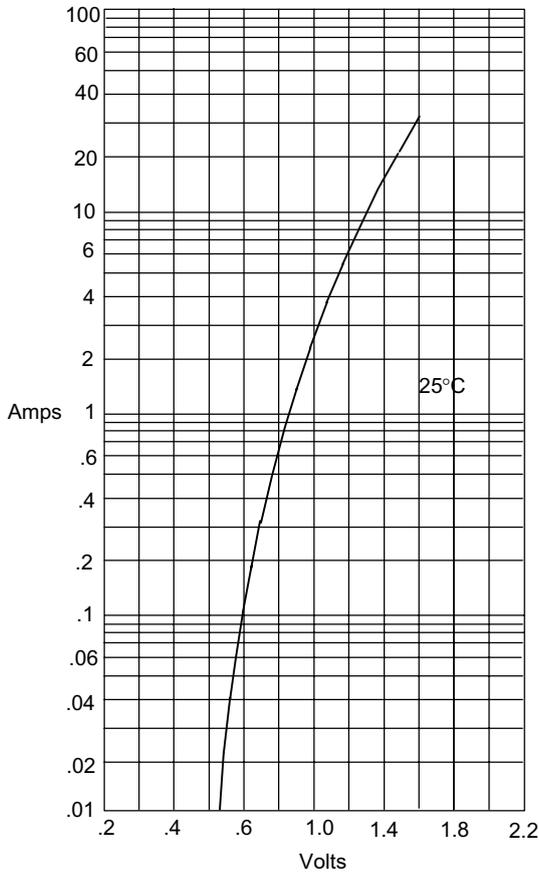


Ordering Information

Part Number	Package	Shipping	Marking Code
MUR1520	TO-220AC	50pcs / Tube	MUR1520

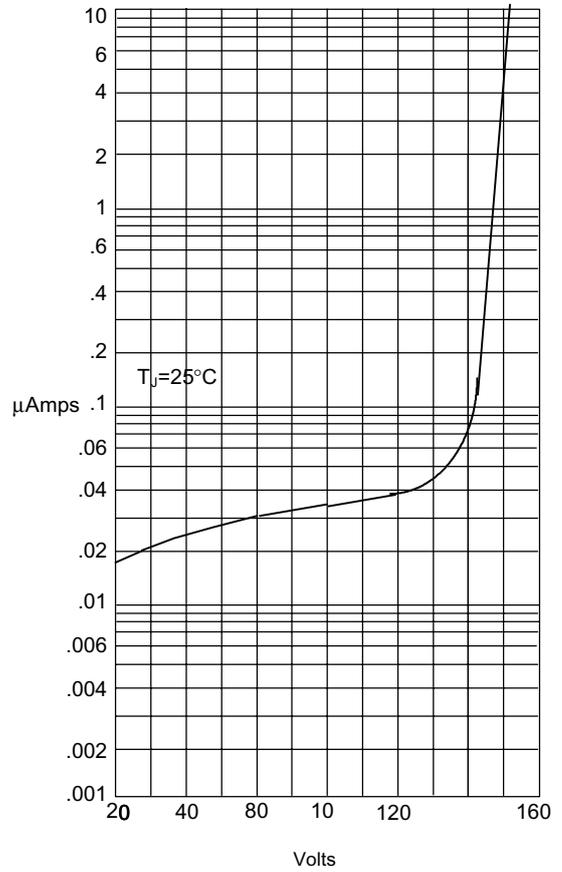
MUR1520

Ultra Fast Recovery Diodes



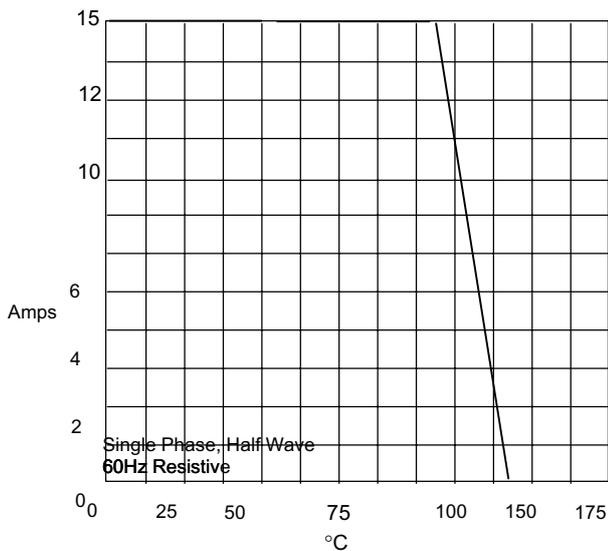
Instantaneous Forward Current - Amperes versus Instantaneous Forward Voltage - Volts

Figure 1 Typical Forward Characteristics



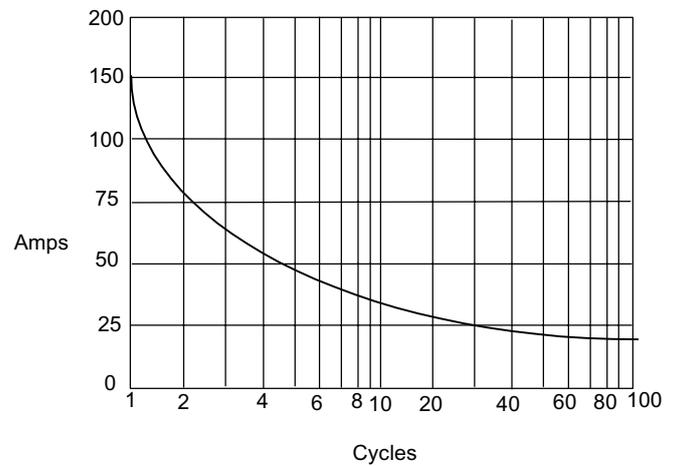
Instantaneous Reverse Leakage Current - MicroAmperes versus Percent Of Rated Peak Reverse Voltage - Volts

Figure 2 Typical Reverse Characteristics



Average Forward Rectified Current - Amperes versus Case Temperature - °C

Figure 3 Forward Derating Curve



Peak Forward Surge Current - Amperes versus Number Of Cycles At 60Hz - Cycles

Figure 4

Maximum Non-Repetitive Forward Surge Current